

TC74HC112AP, TC74HC112AF, TC74HC112AFN

Dual J-K Flip Flop with Preset and Clear

The TC74HC112A is a high speed CMOS DUAL J-K FLIP FLOP fabricated with silicon gate C²MOS technology.

It achieves the high speed operation similar to equivalent LSTTL while maintaining the CMOS low power dissipation.

In accordance with the logic levels applied to the J and K inputs, the outputs change state on the negative going transition of the clock pulse.

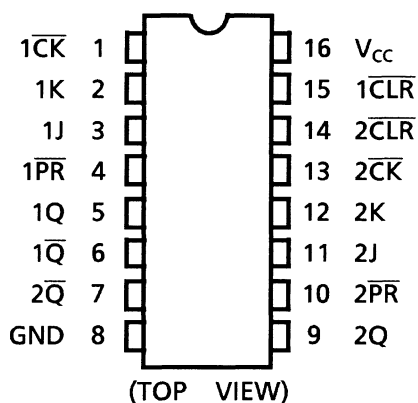
$\overline{\text{CLR}}$ and $\overline{\text{PR}}$ are independent of the clock and are activated by a low logic level on the corresponding input.

All inputs are equipped with protection circuits against static discharge or transient excess voltage.

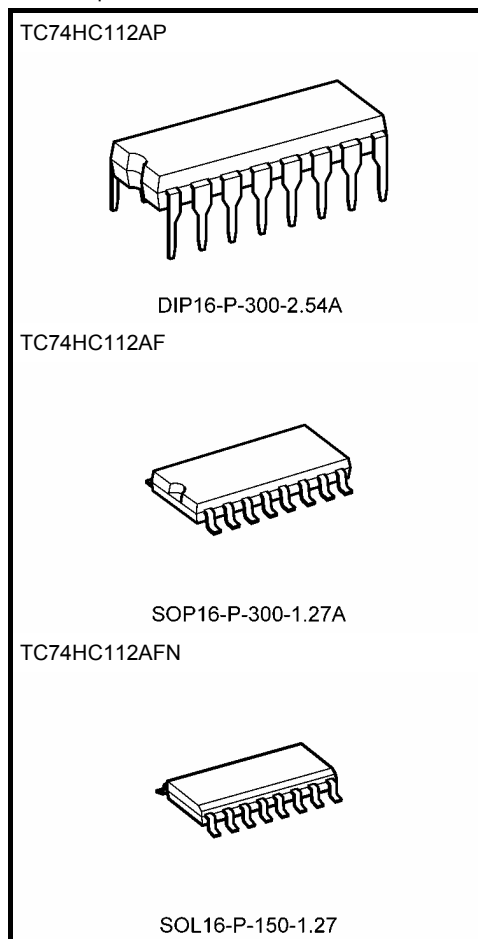
Features

- High speed: $f_{\text{max}} = 67 \text{ MHz}$ (typ.) at $V_{\text{CC}} = 5 \text{ V}$
- Low power dissipation: $I_{\text{CC}} = 2 \mu\text{A}$ (max) at $T_a = 25^\circ\text{C}$
- High noise immunity: $V_{\text{NIH}} = V_{\text{NIL}} = 28\% V_{\text{CC}}$ (min)
- Output drive capability: 10 LSTTL loads
- Symmetrical output impedance: $|I_{\text{OH}}| = I_{\text{OL}} = 4 \text{ mA}$ (min)
- Balanced propagation delays: $t_{\text{pLH}} \approx t_{\text{pHL}}$
- Wide operating voltage range: $V_{\text{CC}} (\text{opr}) = 2 \text{ to } 6 \text{ V}$
- Pin and function compatible with 74LS112

Pin Assignment



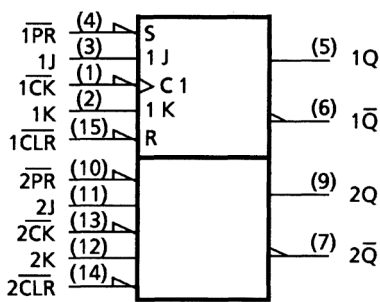
Note: xxxFN (JEDEC SOP) is not available in Japan.



Weight

DIP16-P-300-2.54A	: 1.00 g (typ.)
SOP16-P-300-1.27A	: 0.18 g (typ.)
SOL16-P-150-1.27	: 0.13 g (typ.)

IEC Logic Symbol

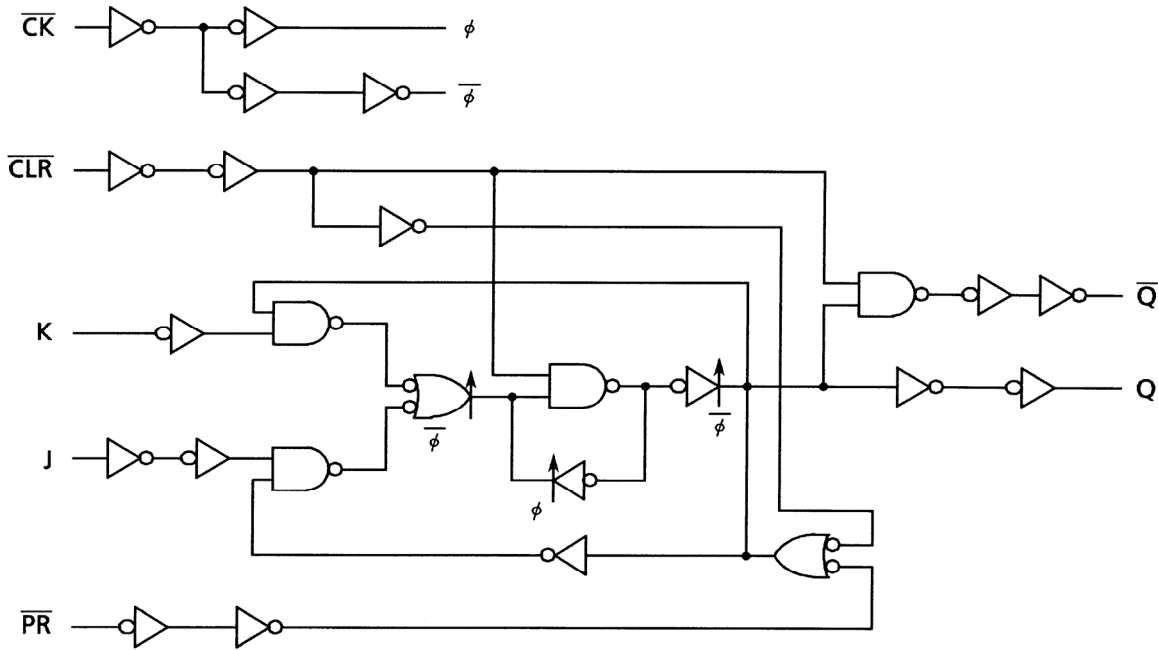


Truth Table

Inputs					Outputs		Function
CLR	PR	J	K	CK	Q	Q̄	
L	H	X	X	X	L	H	Clear
H	L	X	X	X	H	L	Preset
L	L	X	X	X	H	H	
H	H	L	L	↓	Q _n	Q̄ _n	No Change
H	H	L	H	↓	L	H	
H	H	H	L	↓	H	L	
H	H	H	H	↓	Q̄ _n	Q _n	Toggle
H	H	X	X	↑	Q _n	Q̄ _n	No Change

X: Don't care

System Diagram



Absolute Maximum Ratings (Note 1)

Characteristics	Symbol	Rating	Unit
Supply voltage range	V_{CC}	-0.5 to 7	V
DC input voltage	V_{IN}	-0.5 to $V_{CC} + 0.5$	V
DC output voltage	V_{OUT}	-0.5 to $V_{CC} + 0.5$	V
Input diode current	I_{IK}	± 20	mA
Output diode current	I_{OK}	± 20	mA
DC output current	I_{OUT}	± 25	mA
DC V_{CC} /ground current	I_{CC}	± 50	mA
Power dissipation	P_D	500 (DIP) (Note 2)/180 (SOP)	mW
Storage temperature	T_{stg}	-65 to 150	°C

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc.).

Note 2: 500 mW in the range of $T_a = -40$ to 65°C . From $T_a = 65$ to 85°C a derating factor of $-10\text{ mW}/^\circ\text{C}$ shall be applied until 300 mW.

Operating Ranges (Note)

Characteristics	Symbol	Rating	Unit
Supply voltage	V_{CC}	2 to 6	V
Input voltage	V_{IN}	0 to V_{CC}	V
Output voltage	V_{OUT}	0 to V_{CC}	V
Operating temperature	T_{opr}	-40 to 85	°C
Input rise and fall time	t_r, t_f	0 to 1000 ($V_{CC} = 2.0\text{ V}$) 0 to 500 ($V_{CC} = 4.5\text{ V}$) 0 to 400 ($V_{CC} = 6.0\text{ V}$)	ns

Note: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either VCC or GND.

Electrical Characteristics
DC Characteristics

Characteristics	Symbol	Test Condition		Ta = 25°C				Ta = -40 to 85°C		Unit
				VCC (V)	Min	Typ.	Max	Min	Max	
High-level input voltage	V _{IH}	—		2.0 4.5 6.0	1.50 3.15 4.20	— — —	— — —	1.50 3.15 4.20	— — —	V
Low-level input voltage	V _{IL}	—		2.0 4.5 6.0	— — —	— — —	0.50 1.35 1.80	— — —	0.50 1.35 1.80	V
High-level output voltage	V _{OH}	V _{IN} = V _{IH} or V _{IL}	I _{OH} = -20 μA	2.0	1.9	2.0	—	1.9	—	V
				4.5	4.4	4.5	—	4.4	—	
				6.0	5.9	6.0	—	5.9	—	
			I _{OH} = -4 mA	4.5	4.18	4.31	—	4.13	—	
I _{OH} = -5.2 mA	6.0	5.68	5.80	—	5.63	—				
Low-level output voltage	V _{OL}	V _{IN} = V _{IH} or V _{IL}	I _{OL} = 20 μA	2.0	—	0.0	0.1	—	0.1	V
				4.5	—	0.0	0.1	—	0.1	
				6.0	—	0.0	0.1	—	0.1	
			I _{OL} = 4 mA	4.5	—	0.17	0.26	—	0.33	
I _{OL} = 5.2 mA	6.0	—	0.18	0.26	—	0.33				
Input leakage current	I _{IN}	V _{IN} = V _{CC} or GND		6.0	—	—	±0.1	—	±1.0	μA
Quiescent supply current	I _{CC}	V _{IN} = V _{CC} or GND		6.0	—	—	2.0	—	20.0	μA

Timing Requirements (input: $t_r = t_f = 6 \text{ ns}$)

Characteristics	Symbol	Test Condition	Ta = 25°C		Ta = -40 to 85°C	Limit	Unit
			V _{CC} (V)	Typ.			
Minimum pulse width ($\overline{\text{CK}}$)	t_W (L) t_W (H)	—	2.0	—	75	95	ns
			4.5	—	15	19	
			6.0	—	13	16	
Minimum pulse width ($\overline{\text{CLR}}$, $\overline{\text{PR}}$)	t_W (L)	—	2.0	—	75	95	ns
			4.5	—	15	19	
			6.0	—	13	16	
Minimum set-up time	t_s	—	2.0	—	75	95	ns
			4.5	—	15	19	
			6.0	—	13	16	
Minimum hold time	t_h	—	2.0	—	0	0	ns
			4.5	—	0	0	
			6.0	—	0	0	
Minimum removal time ($\overline{\text{CLR}}$, $\overline{\text{PR}}$)	t_{rem}	—	2.0	—	50	60	ns
			4.5	—	10	12	
			6.0	—	9	11	
Clock frequency	f	—	2.0	—	6	4	MHz
			4.5	—	30	24	
			6.0	—	34	28	

AC Characteristics ($C_L = 15 \text{ pF}$, $V_{CC} = 5 \text{ V}$, Ta = 25°C, input: $t_r = t_f = 6 \text{ ns}$)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Output transition time	t_{TLH}	—	—	4	8	ns
	t_{THL}					
Propagation delay time ($\overline{\text{CK}}$ -Q, $\overline{\text{Q}}$)	t_{pLH}	—	—	13	21	ns
	t_{pHL}					
Propagation delay time ($\overline{\text{CLR}}$, $\overline{\text{PR}}$ -Q, $\overline{\text{Q}}$)	t_{pLH}	—	—	15	22	ns
	t_{pHL}					
Maximum clock frequency	f_{max}	—	32	67	—	MHz

AC Characteristics ($C_L = 50 \text{ pF}$, input: $t_r = t_f = 6 \text{ ns}$)

Characteristics	Symbol	Test Condition	V_{CC} (V)	$T_a = 25^\circ\text{C}$			$T_a = -40 \text{ to } 85^\circ\text{C}$		Unit
				Min	Typ.	Max	Min	Max	
Output transition time	t_{TLH}	—	2.0	—	30	75	—	95	ns
	t_{THL}		4.5	—	8	15	—	19	
			6.0	—	7	13	—	16	
Propagation delay time ($\overline{CK} - Q, \overline{Q}$)	t_{pLH}	—	2.0	—	52	125	—	155	ns
	t_{pHL}		4.5	—	16	25	—	31	
			6.0	—	14	21	—	26	
Propagation delay time (\overline{CLR} , $\overline{PR} - Q, \overline{Q}$)	t_{pLH}	—	2.0	—	68	135	—	170	ns
	t_{pHL}		4.5	—	17	27	—	34	
			6.0	—	15	23	—	29	
Maximum clock frequency	f_{max}	—	2.0	6	19	—	4	—	MHz
			4.5	30	63	—	24	—	
			6.0	34	71	—	28	—	
Input capacitance	C_{IN}	—		—	5	10	—	10	pF
Power dissipation capacitance	C_{PD} (Note)	—		—	35	—	—	—	pF

Note: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

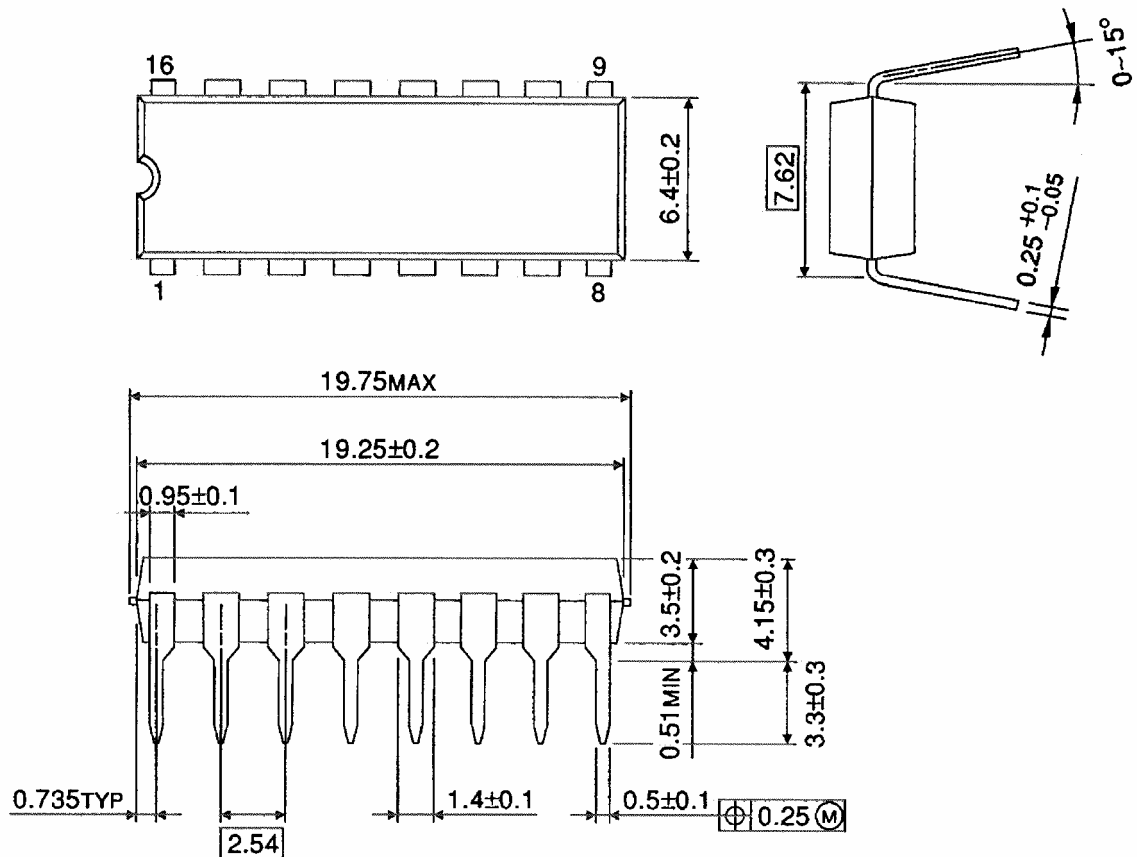
Average operating current can be obtained by the equation:

$$I_{CC}(\text{opr}) = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/2 \text{ (per F/F)}$$

Package Dimensions

DIP16-P-300-2.54A

Unit : mm

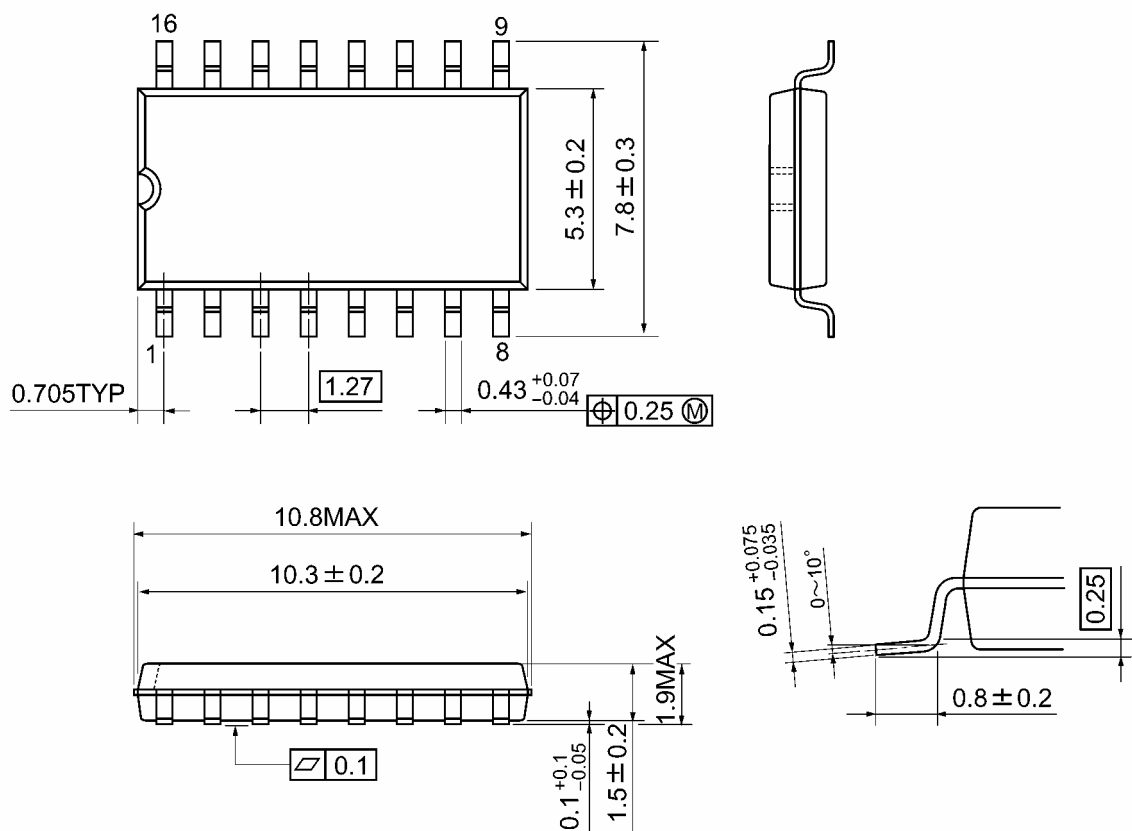


Weight: 1.00 g (typ.)

Package Dimensions

SOP16-P-300-1.27A

Unit: mm

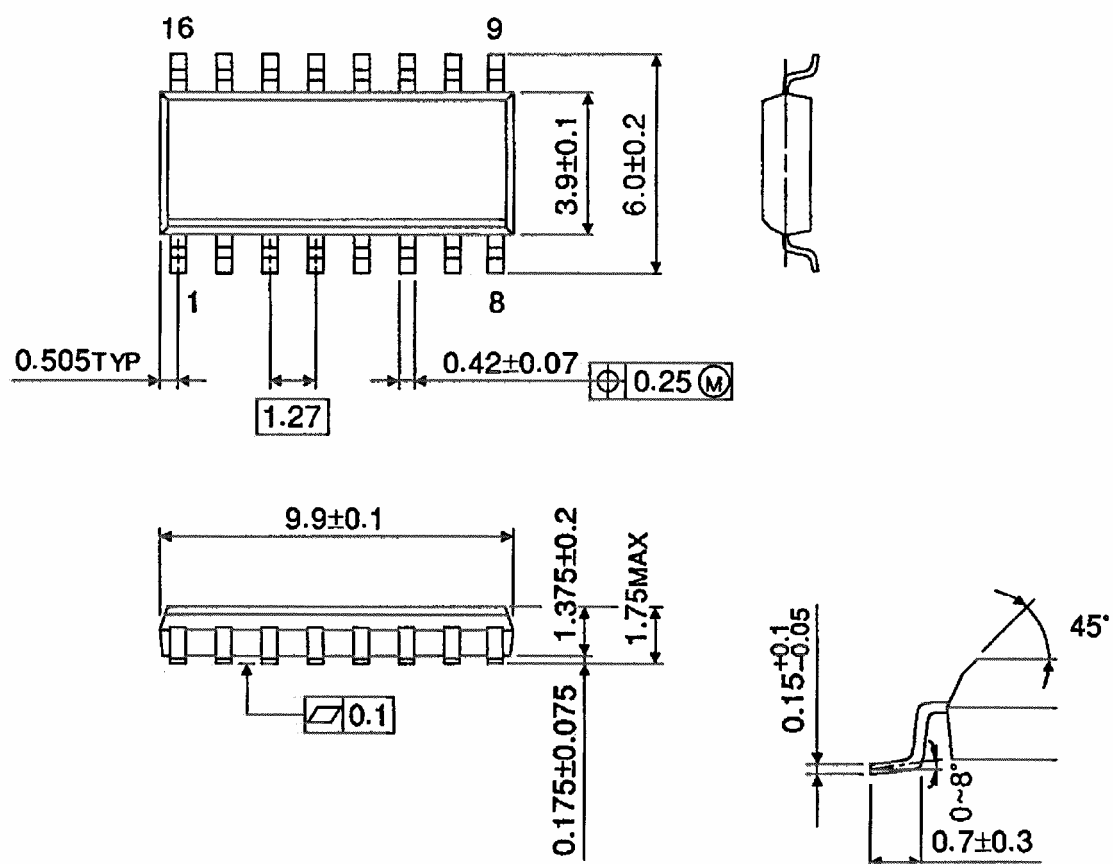


Weight: 0.18 g (typ.)

Package Dimensions (Note)

SOL16-P-150-1.27

Unit : mm



Note: This package is not available in Japan.

Weight: 0.13 g (typ.)

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20070701-EN GENERAL

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